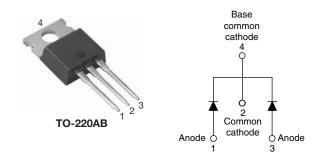
VS-16CTU04HN3

Vishay Semiconductors

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Ultrafast Rectifier, 16 A FRED Pt[®]



PRIMARY CHARACTERISTICS									
I _{F(AV)}	2 x 8 A								
V _R	400 V								
V _F at I _F	0.94 V								
t _{rr} (typ.)	24 ns								
T _J max.	175 °C								
Package	TO-220AB								
Circuit configuration	Common cathode								

FEATURES

- · Ultrafast recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

FRED Pt[®] series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RA	TINGS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		V _{RRM}		400	V
Average rectified forward current	per leg			8	
Average rectilied forward current	total device	I _{F(AV)}	$T_{C} = 155 \text{ °C}, \text{ rated } V_{R}$	16	А
Non-repetitive peak surge current		I _{FSM}	T _C = 25 °C	100	A
Peak repetitive forward current		I _{FRM}	T_{C} = 155 °C, rated V_{R} , square wave, 20 kHz	16	
Operating junction and storage temp	peratures	T _J , T _{Stg}		-65 to +175	°C

ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25 \text{ °C}$ unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	400	-	-				
Converd voltage	VF	I _F = 8 A	-	1.19	1.3	V			
Forward voltage	VF	I _F = 8 A, T _J = 150 °C	-	0.94	1.0				
		V _R = V _R rated	-	0.2	10				
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	500	μA			
Junction capacitance	CT	V _R = 400 V	-	14	-	pF			
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH			

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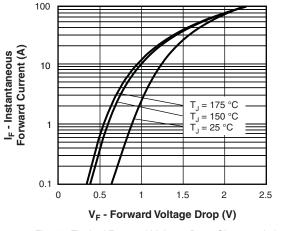
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DYNAMIC RECOVERY CHARACTERISTICS PER LEG (T_J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	50 A/µA, V _R = 30 V	-	35	-				
Reverse recovery time	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	-	24 -	ns					
		T _J = 25 °C		-	43	-	115			
		T _J = 125 °C		-	67	-				
Dook rooovery ourrent		T _J = 25 °C	I _F = 8 A dI _F /dt = 200 A/μs	-	2.8	-	А			
Peak recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm R} = 200 \text{ V}$	-	6.3	-				
Reverse recovery charge	0	T _J = 25 °C		-	60	-	20			
	Q _{rr}	T _J = 125 °C		-	210	-	nC			

THERMAL MECH	THERMAL MECHANICAL SPECIFICATIONS										
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and temperature range	storage	T _J , T _{Stg}		-65	-	175	°C				
Thermal resistance,	per leg	Р		-	3.6	4					
junction to case	per device	R _{thJC}		-	1.8	2					
Thermal resistance, junction to ambient		R _{thJA}	Typical socket mount	-	-	50	°C/W				
Thermal resistance, case to heatsink		R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-	-				
W/aight				-	2.0	-	g				
Weight				-	0.07	-	oz.				
Mounting torque				6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device			Case style TO-220AB	16CTU04H							

VS-16CTU04HN3

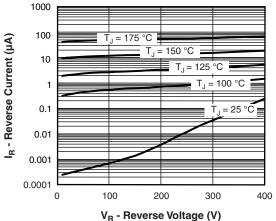
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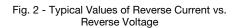


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Fig. 1 - Typical Forward Voltage Drop Characteristics





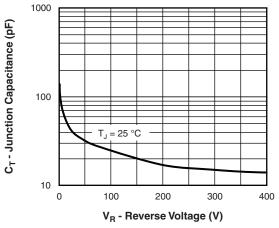


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

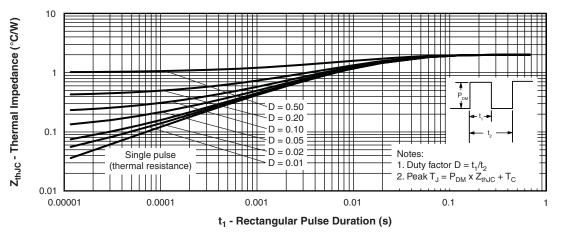
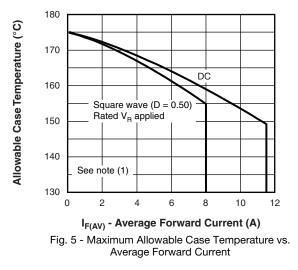
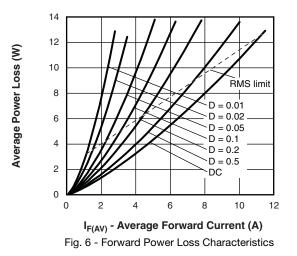


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics







Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \, \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \, x \, \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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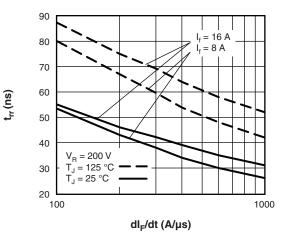


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

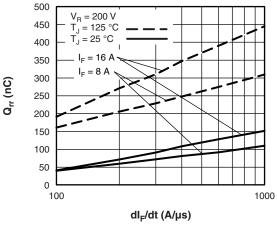
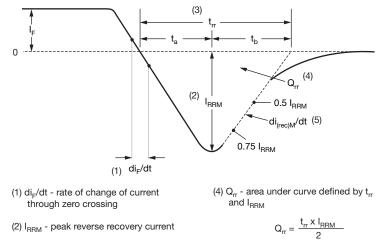


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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(3) $t_{\rm rr}$ - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current. (5) di w/dt - peak rate of change of

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 1 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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Device code	VS-	16	С	т	U	04	н	N3
		(2)	3	4	5	6	(7)	(8)
	1 - 2 -			niconduc ng (16 =		oduct		
	3 -	Circ	uit conf	iguratior	ו:			
	4 -		Commo kage:	on catho	de			
	5 -		TO-220 afast red					
	6 -	Volt	age rati	ng (04 =	= 400 V)			
	7 -			101 qua				
	8 -			ntal digit en-free,		complia	nt, and	totally le

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-16CTU04HN3	50	1000	Antistatic plastic tube							

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95222						
Part marking information	www.vishay.com/doc?95028						
SPICE model	www.vishay.com/doc?96565						

Revision: 21-Sep-2018

5

Document Number: 94720

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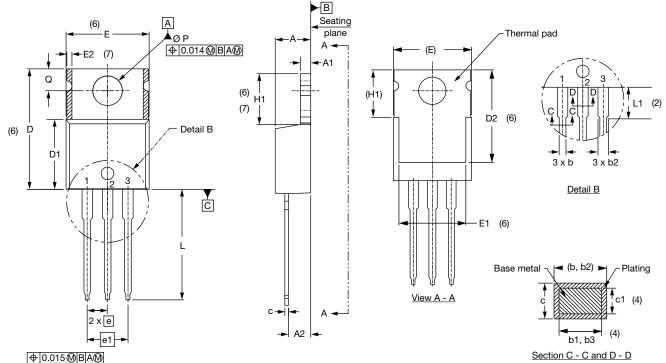
Outline Dimensions



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TO-220AB

DIMENSIONS in millimeters and inches



Lead tip

Conforms to JEDEC[®] outline TO-220AB

SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183			D2	11.68	12.88	0.460	0.507	6
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.56	2.92	0.101	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			E2	-	0.76	-	0.030	7
b1	0.38	0.97	0.015	0.038	4		е	2.41	2.67	0.095	0.105	
b2	1.20	1.73	0.047	0.068			e1	4.88	5.28	0.192	0.208	
b3	1.14	1.73	0.045	0.068	4		H1	5.84	6.86	0.230	0.270	6, 7
с	0.36	0.61	0.014	0.024			L	13.52	14.02	0.532	0.552	
c1	0.36	0.56	0.014	0.022	4		L1	3.32	3.82	0.131	0.150	2
D	14.85	15.25	0.585	0.600	3		ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Dimension b1, b3 and c1 apply to base metal only

⁽⁵⁾ Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1

⁽⁷⁾ Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed

(8) Outline conforms to JEDEC[®] TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

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